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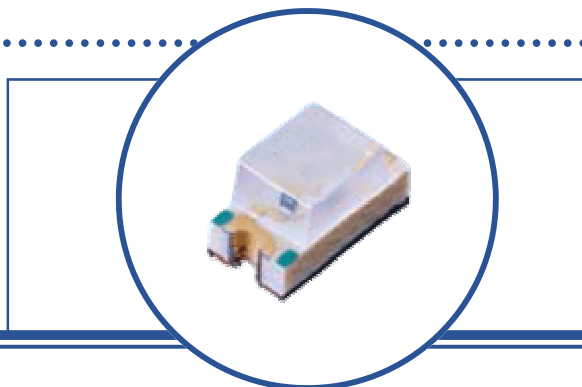
sales@integrated-circuit.com

Infrared Light Emitting Diode in Miniature SMD Package



OP250

- Flat Lens
- High Power
- 1206 Package Size
- 880nm Wavelength

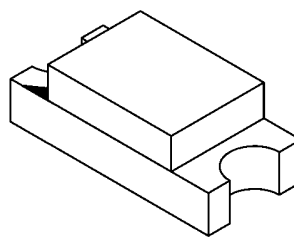
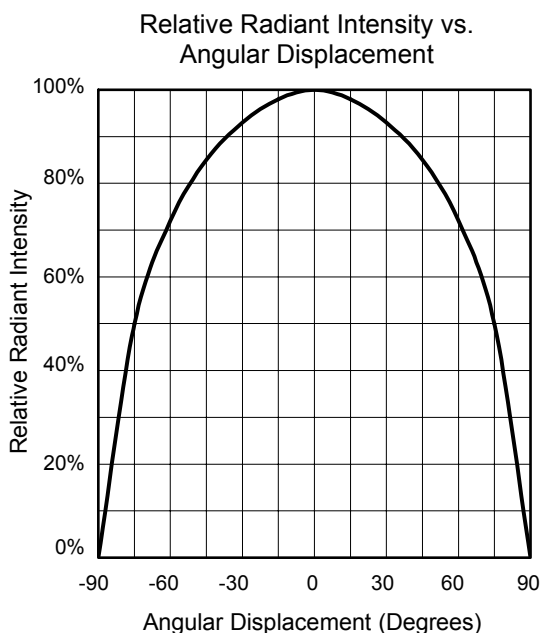


PRELIMINARY

The OP250 is a GaAlAs infrared LEDs mounted in a miniature SMT package. The device incorporates a flat molded lens which enables a wide beam angle and provides an even emission pattern. This device is packaged in a 1206 size chip carrier that is compatible with most automated mounting equipment. The OP250 is mechanically and spectrally matched to the OP520 series phototransistors.

Applications

- Non-Contact Position Sensing
- Machine automation
- Datum detection
- Optical encoders



OP250



LEAD FREE

Optek reserves the right to make changes at any time in order to improve design and to supply the best product possible.

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A subsidiary of
TT electronics plc

SMD Infrared LED

OP250



Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$ unless otherwise noted

Storage Temperature Range	-40° C to +85° C
Operating Temperature Range	-25° C to +85° C
Lead Soldering Temperature	260° C ⁽¹⁾
Reverse Voltage	30 V
Continuous Forward Current	50 mA
Power Dissipation	130 mW ⁽²⁾

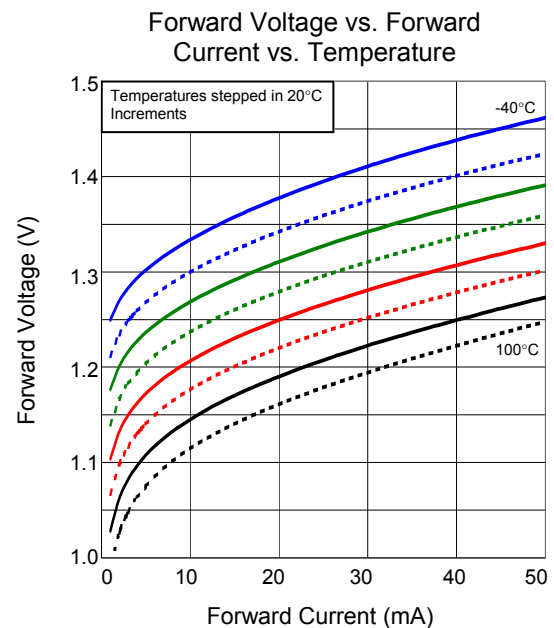
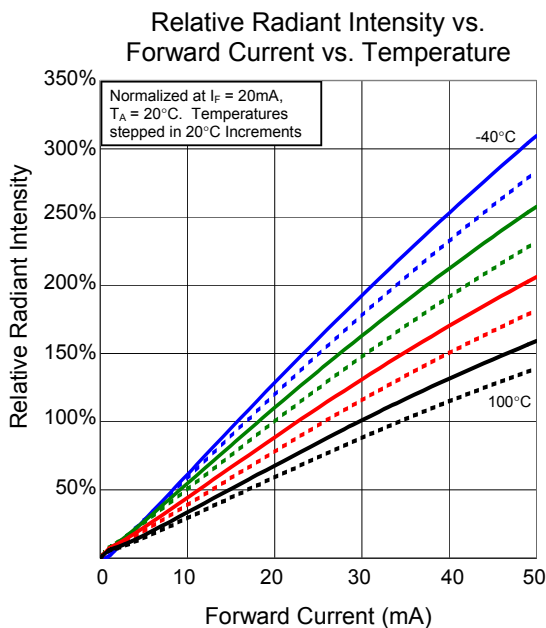
Notes:

- Solder time less than 5 seconds at temperature extreme.
- De-rate linearly at 2.17 mW/° C above 25° C.

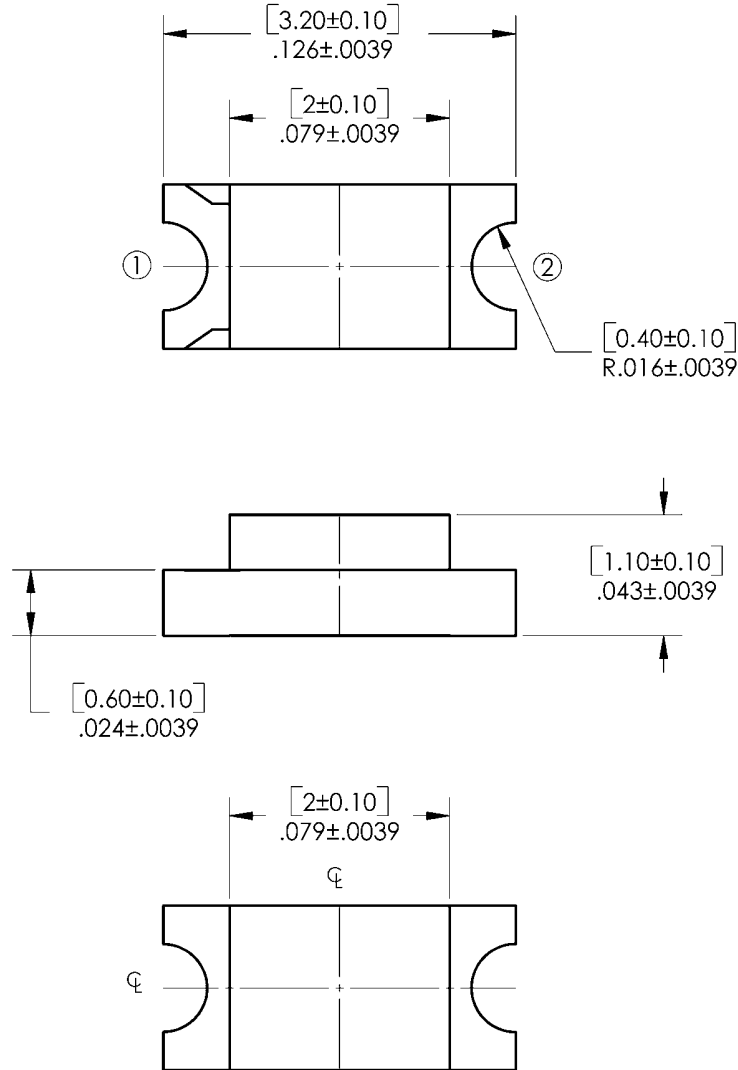
Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	CONDITIONS
$E_{e(APT)}$	Apertured Radiant Incidence	0.2			mW/cm ²	$I_F = 20\text{mA}^{(3)}$
V_F	Forward Voltage			1.5	V	$I_F = 20\text{mA}$
I_R	Reverse Current			100	μA	$V_R = 2.0\text{V}$
λ_P	Peak Emission Wavelength		890		nm	$I_F = 10\text{mA}$
Θ_{HP}	Emission Angle at Half Power Points		150		Deg.	$I_F = 20\text{mA}$
t_r, t_f	Rise and Fall Time			500	ns	$I_{F(PEAK)} = 100\text{mA}, \text{PW} = 10\mu\text{s}, 10\% \text{ D.C.}$

- $E_{e(APT)}$ is a measurement of the apertured radiant incidence upon a sensing area 0.081" (2.06mm) in diameter, perpendicular to and centered on the mechanical axis of the lens, and 0.590" (14.99mm) from the measurement surface. $E_{e(APT)}$ is not necessarily uniform within the measured area.



SMD Infrared LED
OP250



DIMENSIONS ARE IN INCHES AND [MILLIMETERS].

RECOMMENDED SOLDER PADS

